NSN 5961-01-030-7250

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-030-7250 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1200.0 nonrepetitive peak reverse voltage, peak total value and 1000.0 working peak reverse voltage, peak total value and 1000.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 500.00 amperes forward current, average preset and 35.00 amperes forward current, average absolute **Test Data Document:** 10001-2896581 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: